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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I ² C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, Cap Sense, DMA, I2S, LCD, POR, PWM, WDT
Number of I/O	83
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 24x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-UFBGA
Supplier Device Package	100-UFBGA (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l152v8h6a

2 Description

The ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A devices incorporate the connectivity power of the universal serial bus (USB) with the high-performance ARM[®] Cortex[®]-M3 32-bit RISC core operating at a frequency of 32 MHz (33.3 DMIPS), a memory protection unit (MPU), high-speed embedded memories (Flash memory up to 128 Kbytes and RAM up to 32 Kbytes) and an extensive range of enhanced I/Os and peripherals connected to two APB buses.

All the devices offer a 12-bit ADC, 2 DACs and 2 ultra-low-power comparators, six general-purpose 16-bit timers and two basic timers, which can be used as time bases.

Moreover, the STM32L151x6/8/B-A and STM32L152x6/8/B-A devices contain standard and advanced communication interfaces: up to two I²Cs and SPIs, three USARTs and a USB. The STM32L151x6/8/B-A and STM32L152x6/8/B-A devices offer up to 20 capacitive sensing channels to simply add touch sensing functionality to any application.

They also include a real-time clock with sub-second counting and a set of backup registers that remain powered in Standby mode.

Finally, the integrated LCD controller (except STM32L151x6/8/B-A devices) has a built-in LCD voltage generator that allows to drive up to 8 multiplexed LCDs with contrast independent of the supply voltage.

The ultra-low-power STM32L151x6/8/B-A and STM32L152x6/8/B-A devices operate from a 1.8 to 3.6 V power supply (down to 1.65 V at power down) with BOR and from a 1.65 to 3.6 V power supply without BOR option. They are available in the -40 to +85 °C and -40 to +105°C temperature ranges. A comprehensive set of power-saving modes allows the design of low-power applications.







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3.4 Clock management

The clock controller distributes the clocks coming from different oscillators to the core and the peripherals. It also manages clock gating for low-power modes and ensures clock robustness. It features:

- Clock prescaler: to get the best trade-off between speed and current consumption, the clock frequency to the CPU and peripherals can be adjusted by a programmable prescaler
- **Safe clock switching**: clock sources can be changed safely on the fly in run mode through a configuration register.
- **Clock management**: to reduce power consumption, the clock controller can stop the clock to the core, individual peripherals or memory.
- Master clock source: three different clock sources can be used to drive the master clock:
 - 1-24 MHz high-speed external crystal (HSE), that can supply a PLL
 - 16 MHz high-speed internal RC oscillator (HSI), trimmable by software, that can supply a PLL
 - Multispeed internal RC oscillator (MSI), trimmable by software, able to generate 7 frequencies (65.5 kHz, 131 kHz, 262 kHz, 524 kHz, 1.05 MHz, 2.1 MHz, 4.2 MHz) with a consumption proportional to speed, down to 750 nA typical. When a 32.768 kHz clock source is available in the system (LSE), the MSI frequency can be trimmed by software down to a ±0.5% accuracy.
- Auxiliary clock source: two ultra-low-power clock sources that can be used to drive the LCD controller and the real-time clock:
 - 32.768 kHz low-speed external crystal (LSE)
 - 37 kHz low-speed internal RC (LSI), also used to drive the independent watchdog.
 The LSI clock can be measured using the high-speed internal RC oscillator for greater precision.
- RTC and LCD clock sources: the LSI, LSE or HSE sources can be chosen to clock the RTC and the LCD, whatever the system clock.
- **USB clock source:** the embedded PLL has a dedicated 48 MHz clock output to supply the USB interface.
- **Startup clock:** after reset, the microcontroller restarts by default with an internal 2.1 MHz clock (MSI). The prescaler ratio and clock source can be changed by the application program as soon as the code execution starts.
- Clock security system (CSS): this feature can be enabled by software. If a HSE clock failure occurs, the master clock is automatically switched to HSI and a software interrupt is generated if enabled.
- Clock-out capability (MCO: microcontroller clock output): it outputs one of the internal clocks for external use by the application.

Several prescalers allow the configuration of the AHB frequency, the high-speed APB (APB2) and the low-speed APB (APB1) domains. The maximum frequency of the AHB and the APB domains is 32 MHz. See *Figure 2* for details on the clock tree.



3.5 Low-power real-time clock and backup registers

The real-time clock (RTC) is an independent BCD timer/counter. Dedicated registers contain the sub-second, second, minute, hour (12/24 hour), week day, date, month, year, in BCD (binary-coded decimal) format. Correction for 28, 29 (leap year), 30, and 31 day of the month are made automatically. The RTC provides two programmable alarms and programmable periodic interrupts with wakeup from Stop and Standby modes.

The programmable wakeup time ranges from 120 µs to 36 hours.

The RTC can be calibrated with an external 512 Hz output, and a digital compensation circuit helps reduce drift due to crystal deviation. The RTC can also be automatically corrected with a 50/60Hz stable power line.

The RTC calendar can be updated on the fly down to sub second precision, which enables network system synchronization. A time stamp can record an external event occurrence, and generates an interrupt.

There are twenty 32-bit backup registers provided to store 80 bytes of user application data. They are cleared in case of tamper detection. Three pins can be used to detect tamper events. A change on one of these pins can reset backup register and generate an interrupt. To prevent false tamper event, like ESD event, these three tamper inputs can be digitally filtered.

3.6 GPIOs (general-purpose inputs/outputs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions, and can be individually remapped using dedicated AFIO registers. All GPIOs are high current capable. The alternate function configuration of I/Os can be locked if needed following a specific sequence in order to avoid spurious writing to the I/O registers. The I/O controller is connected to the AHB with a toggling speed of up to 16 MHz.

External interrupt/event controller (EXTI)

The external interrupt/event controller consists of 23 edge detector lines used to generate interrupt/event requests. Each line can be individually configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the Internal APB2 clock period. Up to 83 GPIOs can be connected to the 16 external interrupt lines. The 7 other lines are connected to RTC, PVD, USB or Comparator events.



3.15.5 Window watchdog (WWDG)

The window watchdog is based on a 7-bit down-counter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in debug mode.

3.16 Communication interfaces

3.16.1 I2C bus

Up to two I²C bus interfaces can operate in multimaster and slave modes. They can support standard and fast modes.

They support dual slave addressing (7-bit only) and both 7- and 10-bit addressing in master mode. A hardware CRC generation/verification is embedded.

They can be served by DMA and they support SM Bus 2.0/PM Bus.

3.16.2 Universal synchronous/asynchronous receiver transmitter (USART)

All USART interfaces are able to communicate at speeds of up to 4 Mbit/s. They provide hardware management of the CTS and RTS signals and are ISO 7816 compliant. They support IrDA SIR ENDEC and have LIN Master/Slave capability.

All USART interfaces can be served by the DMA controller.

3.16.3 Serial peripheral interface (SPI)

Up to two SPIs are able to communicate at up to 16 Mbits/s in slave and master modes in full-duplex and half-duplex communication modes. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes.

Both SPIs can be served by the DMA controller.

3.16.4 Universal serial bus (USB)

The STM32L151x6/8/B-A and STM32L152x6/8/B-A devices embed a USB device peripheral compatible with the USB full speed 12 Mbit/s. The USB interface implements a full speed (12 Mbit/s) function interface. It has software-configurable endpoint setting and supports suspend/resume. The dedicated 48 MHz clock is generated from the internal main PLL (the clock source must use a HSE crystal oscillator).

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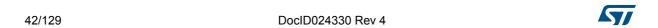
Table 9. STM32L151x6/8/B-A and STM32L152x6/8/B-A pin definitions (continued)

		Pins	;						Pins functio	ns
LQFP100	LQFP64	TFBGA64	UFBGA100	LQFP48 or UFQFPN48	Pin name	Pin type ⁽¹⁾	I/O structure	Main function ⁽²⁾ (after reset)	Alternate functions	Additional functions
35	26	F5	M5	18	PB0	I/O	TC	PB0	TIM3_CH3/ LCD_SEG5	ADC_IN8/ COMP1_INP/ VREF_OUT /VLCDRAIL3
36	27	G5	M6	19	PB1	I/O	FT	PB1	TIM3_CH4/ LCD_SEG6	ADC_IN9/ COMP1_INP/ VREF_OUT
37	28	G6	L6	20	PB2	I/O	FT	PB2/ BOOT1	BOOT1	VLCDRAIL1
38	-	-	M7	-	PE7	I/O	TC	PE7	-	ADC_IN22/ COMP1_INP
39	-	ı	L7	-	PE8	I/O	TC	PE8	-	ADC_IN23/ COMP1_INP
40	-	-	M8	-	PE9	I/O	TC	PE9	TIM2_CH1_ETR	ADC_IN24/ COMP1_INP
41	-	1	L8	-	PE10	I/O	TC	PE10	TIM2_CH2	ADC_IN25/ COMP1_INP
42	-	-	M9	-	PE11	I/O	FT	PE11	TIM2_CH3	VLCDRAIL2
43	-	-	L9	-	PE12	I/O	FT	PE12	TIM2_CH4/ SPI1_NSS	VLCDRAIL3
44	-	-	M10	-	PE13	I/O	FT	PE13	SPI1_SCK	-
45	-	-	M11	-	PE14	I/O	FT	PE14	SPI1_MISO	-
46	-	-	M12	-	PE15	I/O	FT	PE15	SPI1_MOSI	-
47	29	G7	L10	21	PB10	I/O	FT	PB10	I2C2_SCL/USART3_TX /TIM2_CH3/ LCD_SEG10	-
48	30	H7	L11	22	PB11	I/O	FT	PB11	I2C2_SDA/USART3_RX /TIM2_CH4/ LCD_SEG11	-
49	31	D6	F12	23	V _{SS_1}	S	-	V _{SS_1}	-	-
50	32	E6	G12	24	V _{DD_1}	S	-	V _{DD_1}	-	-



Table 9. STM32L151x6/8/B-A and STM32L152x6/8/B-A pin definitions (continued)

		Pins	i						Pins functio	ns
LQFP100	LQFP64	TFBGA64	UFBGA100	LQFP48 or UFQFPN48	Pin name	Pin type ⁽¹⁾	I/O structure	Main function ⁽²⁾ (after reset)	Alternate functions	Additional functions
51	33	Н8	L12	25	PB12	I/O	FT	PB12	SPI2_NSS/I2C2_SMBA/ USART3_CK/ LCD_SEG12/ TIM10_CH1	ADC_IN18/ COMP1_INP /VLCDRAIL2
52	34	G8	K12	26	PB13	I/O	FT	PB13	SPI2_SCK/ USART3_CTS/ LCD_SEG13/TIM9_CH1	ADC_IN19/ COMP1_INP
53	35	F8	K11	27	PB14	I/O	FT	PB14	SPI2_MISO/ USART3_RTS/ LCD_SEG14/TIM9_CH2	ADC_IN20/ COMP1_INP
54	36	F7	K10	28	PB15	I/O	FT	PB15	SPI2_MOSI/ LCD_SEG15/ TIM11_CH1	ADC_IN21/ COMP1_INP/ RTC_REFIN
55	-	-	K9	-	PD8	I/O	FT	PD8	USART3_TX/ LCD_SEG28	-
56	-	1	K8	-	PD9	1/0	FT	PD9	USART3_RX/ LCD_SEG29	-
57	-	-	J12	-	PD10	I/O	FT	PD10	USART3_CK/ LCD_SEG30	-
58	-	-	J11	-	PD11	I/O	FT	PD11	USART3_CTS/ LCD_SEG31	-
59	-	-	J10	-	PD12	I/O	FT	PD12	TIM4_CH1/ USART3_RTS/ LCD_SEG32	-
60	-	-	H12	-	PD13	I/O	FT	PD13	TIM4_CH2/LCD_SEG33	-
61	-	-	H11	-	PD14	I/O	FT	PD14	TIM4_CH3/LCD_SEG34	-
62	-	-	H10	-	PD15	I/O	FT	PD15	TIM4_CH4/LCD_SEG35	-
63	37	F6	E12	-	PC6	I/O	FT	PC6	TIM3_CH1/LCD_SEG24	-
64	38	E7	E11	-	PC7	I/O	FT	PC7	TIM3_CH2/LCD_SEG25	-
65	39	E8	E10	-	PC8	I/O	FT	PC8	TIM3_CH3/LCD_SEG26	-
66	40	D8	D12	-	PC9	I/O	FT	PC9	TIM3_CH4/LCD_SEG27	-



						Digital alterna	te function	number							
Don't many	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFOI6	AFIO7	AFI O8	AFI O9	AFIO11	AFIO 12	AFIO 13	AFIO14	AFIO15
Port name		Alternate function													
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART 1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
воото	воото	-	-	-	-	-	-	-	-	-	-	-	-	-	-
NRST	NRST	-	-	-	-	-	-	-	-	-	-	-	-	-	-
PA0-WKUP1	=	TIM2_CH1_ETR	-	-	-	-	-	USART2_CTS	-	-	-	-	-	TIMx_IC1	EVENTOUT
PA1	-	TIM2_CH2	-	-	-	-	-	USART2_RTS	-	-	[SEG0]	-	-	TIMx_IC2	EVENTOUT
PA2	-	TIM2_CH3	-	TIM9_CH1	-	-	-	USART2_TX	-	-	[SEG1]	-	-	TIMx_IC3	EVENTOUT
PA3	-	TIM2_CH4	-	TIM9_CH2	-	-	-	USART2_RX	-	-	[SEG2]	-	-	TIMx_IC4	EVENTOUT
PA4	-	-	-	-	-	SPI1_NSS	-	USART2_CK	-	-	-	-	-	TIMx_IC1	EVENTOUT
PA5	-	TIM2_CH1_ETR	-	-	-	SPI1_SCK	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PA6	-	-	TIM3_CH1	TIM10_CH1	-	SPI1_MISO	-	-	-	-	[SEG3]	-	-	TIMx_IC3	EVENTOUT
PA7	-	-	TIM3_CH2	TIM11_CH1	-	SPI1_MOSI	-	-	-	-	[SEG4]	-	-	TIMx_IC4	EVENTOUT
PA8	МСО	-	-	-	-	-	-	USART1_CK	-	-	[COM0]	-	-	TIMx_IC1	EVENTOUT
PA9	-	-	-	-	-	-	-	USART1_TX	-	-	[COM1]	-	-	TIMx_IC2	EVENTOUT
PA10	-	-	-	-	-	-	-	USART1_RX	-	-	[COM2]	-	-	TIMx_IC3	EVENTOUT
PA11	-	-	-	-	-	SPI1_MISO	-	USART1_CTS	-	-	-	-	-	TIMx_IC4	EVENTOUT
PA12	-	-	-	-	-	SPI1_MOSI	-	USART1_RTS	-	-	-	-	-	TIMx_IC1	EVENTOUT
PA13	JTMS- SWDIO	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PA14	JTCK- SWCLK	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PA15	JTDI	TIM2_CH1_ETR	-	-	-	SPI1_NSS	-	-	-	-	SEG17	-	-	TIMx_IC4	EVENTOUT
PB0	-	-	TIM3_CH3	-	-	-	-	-	-	-	[SEG5]	-	-	-	EVENTOUT
PB1	-	-	TIM3_CH4	-	-	-	-	-	-	-	[SEG6]	-	-	-	EVENTOUT
PB2	BOOT1	-	-	-	-	-	-	-	-	-	-	-	-	-	EVENTOUT
PB3	JTDO	TIM2_CH2	-	-	-	SPI1_SCK	-	-	-	-	[SEG7]	-	-	-	EVENTOUT





Table 10. Alternate function input/output (continued)

						Digital alterna	te function	number							
Post some	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFOI6	AFIO7	AFI O8	AFI O9	AFIO11	AFIO 12	AFIO 13	AFIO14	AFIO15
Port name		Alternate function													
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART 1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
PB4	NJTRST	=	TIM3_CH1	-	-	SPI1_MISO	-	-	-	-	[SEG8]	-	-	-	EVENTOUT
PB5	-	-	TIM3_CH2	-	I2C1_ SMBA	SPI1_MOSI	-	-	-	-	[SEG9]	-	-	-	EVENTOUT
PB6	=	-	TIM4_CH1	-	I2C1_SCL	-	-	USART1_TX	-	-	-	-	-	-	EVENTOUT
PB7	-	-	TIM4_CH2	-	I2C1_SDA	-	-	USART1_RX	-	-	-	-	-	-	EVENTOUT
PB8	-	-	TIM4_CH3	TIM10_CH1*	I2C1_SCL	-	-	-	-	-	SEG16	-	-	-	EVENTOUT
PB9	-	-	TIM4_CH4	TIM11_CH1*	I2C1_SDA	-	-	-	-	-	[COM3]	-	-	-	EVENTOUT
PB10	=	TIM2_CH3	-	-	I2C2_SCL	-	-	USART3_TX	-	-	SEG10	-	-	-	EVENTOUT
PB11	-	TIM2_CH4	-	-	I2C2_SDA	-	-	USART3_RX	-	-	SEG11	-	-	-	EVENTOUT
PB12	-	-	-	TIM10_CH1	I2C2_ SMBA	SPI2_NSS	-	USART3_CK	-	-	SEG12	-	-	-	EVENTOUT
PB13	-	-	-	TIM9_CH1	-	SPI2_SCK	-	USART3_CTS	-	-	SEG13	-	-	-	EVENTOUT
PB14	-	-	-	TIM9_CH2	-	SPI2_MISO	-	USART3_RTS	-	-	SEG14	-	-	-	EVENTOUT
PB15	-	-	-	TIM11_CH1	-	SPI2_MOSI	-	-	-	-	SEG15	-	-	-	EVENTOUT
PC0	-	-	-	-	-	-	-	-	-	-	SEG18	-	-	TIMx_IC1	EVENTOUT
PC1	-	-	-	-	-	-	-	-	-	-	SEG19	-	-	TIMx_IC2	EVENTOUT
PC2	-	-	-	-	-	-	-	-	-	-	SEG20	-	-	TIMx_IC3	EVENTOUT
PC3	-	-	-	-	-	-	-	-	-	-	SEG21	-	-	TIMx_IC4	EVENTOUT
PC4	-	-	-	-	-	-	-	-	-	-	SEG22	-	-	TIMx_IC1	EVENTOUT
PC5	-	-	-	-	-	-	-	-	-	-	SEG23	-	-	TIMx_IC2	EVENTOUT
PC6	=	-	TIM3_CH1	-	-	-	-	-	-	-	SEG24	-	-	TIMx_IC3	EVENTOUT
PC7	-	-	TIM3_CH2	-	-	-	-	-	-	-	SEG25	-	-	TIMx_IC4	EVENTOUT
PC8	-	-	TIM3_CH3	-	-	-	-	-	-	-	SEG26	-	-	TIMx_IC1	EVENTOUT
PC9	-	-	TIM3_CH4	-	-	-	-	-	-	-	SEG27	-	-	TIMx_IC2	EVENTOUT

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Table 10. Alternate function input/output (continued)

						Digital alterna	te function	number							
Port name	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFOI6	AFIO7	AFI O8	AFI O9	AFIO11	AFIO 12	AFIO 13	AFIO14	AFIO15
Port name						Altern	ate functio	n							
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART 1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
PD10	-	-	-	-	-	-	-	USART3_CK	-	-	-	-	-	TIMx_IC3	EVENTOUT
PD11	-	-	-	-	-	-	-	USART3_CTS	-	-	-	-	-	TIMx_IC4	EVENTOUT
PD12	-	-	TIM4_CH1	-	-	-	-	USART3_RTS	-	-	-	-	-	TIMx_IC1	EVENTOUT
PD13	-	-	TIM4_CH2	-	-	-	-	-	-	1	-	-	-	TIMx_IC2	EVENTOUT
PD14	-	-	TIM4_CH3	-	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PD15	-	-	TIM4_CH4	-	-	-	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PE0	-	-	TIM4_ETR	TIM10_CH1	-	-	-	-	-	1	-	-	-	TIMx_IC1	EVENTOUT
PE1	-	-		TIM11_CH1	-	-	-	-	-	1	-	-	-	TIMx_IC2	EVENTOUT
PE2	TRACECK	-	TIM3_ETR	-	-	-	-	-	-	1	-	-	-	TIMx_IC3	EVENTOUT
PE3	TRACED0	-	TIM3_CH1	-	-	-	-	-	-	1	-	-	-	TIMx_IC4	EVENTOUT
PE4	TRACED1	-	TIM3_CH2	-	-	-	-	-	-	1	-	-	-	TIMx_IC1	EVENTOUT
PE5	TRACED2	-	-	TIM9_CH1*	-	-	-	-	-	1	-	-	-	TIMx_IC2	EVENTOUT
PE6	TRACED3	-	-	TIM9_CH2*	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PE7	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PE8	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC1	EVENTOUT
PE9	-	TIM2_CH1_ETR	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PE10	-	TIM2_CH2	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PE11	-	TIM2_CH3	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PE12	-	TIM2_CH4	-	-	-	SPI1_NSS	-	-	-	-	-	-	-	TIMx_IC1	EVENTOUT
PE13	-	-	-	-	-	SPI1_SCK	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PE14	-	-	-	-	-	SPI1_MISO	1	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PE15	-	-	-	-	-	SPI1_MOSI	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PH0- OSC_IN	-	-	-	-	-	-	-	-	-	-	-	_	-	-	-

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Table 10. Alternate function input/output (continued)

		Digital alternate function number													
Port name	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFOI6	AFIO7	AFI O8	AFI O9	AFIO11	AFIO 12	AFIO 13	AFIO14	AFIO15
Port name	Alternate function														
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART 1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
PH1- OSC_OUT	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-
PH2	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-



6.1.6 Power supply scheme

Standby-power circuitry (OSC32K,RTC, Wake-up logic RTC backup registers) Ю GP I/Os Logic Kernel logic (CPU, Digital & Memories) Regulator N × 100 nF + 1 × 10 µF V_{SS1/2/.../N} 100 nF Analog: + 1 µF ADC/ RCs, 100 nF V_{REF} DAC PLL, MS32461V1

Figure 12. Power supply scheme

6.1.7 Optional LCD power supply scheme

Option 1

Option 2

Cext

PB0 or PE12

PB12 or PE11

VLCDrail2

VLCDrail2

VSEL

Step-up

Converter

VLCD

PB2

VLCDrail2

VLCDrail2

VLCDrail4

MS32485V1

Figure 13. Optional LCD power supply scheme

- 1. Option 1: LCD power supply is provided by a dedicated VLCD supply source, VSEL switch is open.
- Option 2: LCD power supply is provided by the internal step-up converter, VSEL switch is closed, an external capacitance is needed for correct behavior of this converter.

6.1.8 Current consumption measurement

N x 100 nF +1 x 10 µF N x V_{DD} N x V_{SS} V_{DD} V_{DDA} V_{REF} V_{REF} V_{SSA}

Figure 14. Current consumption measurement scheme

Symbol	Parameter	Conditions		Typ ⁽¹⁾	Max (1)(2)	Unit
			T _A = -40 °C to 25 °C V _{DD} = 1.8 V	0.865	-	
		RTC clocked by LSI (no	T _A = -40 °C to 25 °C	1.11	1.9	
		independent watchdog)	T _A = 55 °C	1.15	2.2	
			T _A = 85 °C	1.35	4	
I_{DD}	Supply current in Standby		T _A = 105 °C	1.93	8.3 ⁽³⁾	
(Standby with RTC)	mode with RTC enabled		T _A = -40 °C to 25 °C V _{DD} = 1.8 V	0.97	-	
		RTC clocked by LSE (no	T _A = -40 °C to 25 °C	1.28	-	
		independent watchdog) ⁽⁴⁾	T _A = 55 °C	1.4	-	μΑ
			T _A = 85 °C	1.7	-	
			T _A = 105 °C	2.34	-	
		Independent watchdog and LSI enabled	T _A = -40 °C to 25 °C	1.0	1.7	
I _{DD}	Supply current in Standby		T _A = -40 °C to 25 °C	0.277	0.6	
(Standby)	mode with RTC disabled	Independent watchdog	T _A = 55 °C	0.31	0.9	
		and LSI OFF	T _A = 85 °C	0.52	2.75	
			T _A = 105 °C	1.09	7 ⁽³⁾	
I _{DD (WU} from Standby)	RMS supply current during wakeup time when exiting from Standby mode	-	V _{DD} = 3.0 V T _A = -40 °C to 25 °C	1	-	mA

Table 24. Typical and maximum current consumptions in Standby mode

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On-chip peripheral current consumption

The current consumption of the on-chip peripherals is given in the following table. The MCU is placed under the following conditions:

- all I/O pins are in input mode with a static value at V_{DD} or V_{SS} (no load)
- all peripherals are disabled unless otherwise mentioned
- the given value is calculated by measuring the current consumption
 - with all peripherals clocked off
 - with only one peripheral clocked on

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^{1.} The typical values are given for V_{DD} = 3.0 V and max values are given for V_{DD} = 3.6 V, unless otherwise specified.

^{2.} Guaranteed by characterization results, unless otherwise specified.

Guaranteed by test in production. 3.

Based on characterization done with a 32.768 kHz crystal (MC306-G-06Q-32.768, manufacturer JFVNY) with two 6.8pF loading capacitors.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
С	Recommended load capacitance versus equivalent serial resistance of the crystal (R _S) ⁽³⁾	R _S = 30 Ω	-	20	-	pF
I _{HSE}	HSE driving current	V _{DD} = 3.3 V, V _{IN} = V _{SS} with 30 pF load	-	-	3	mA
	HSE oscillator power	C = 20 pF $f_{OSC} = 16 \text{ MHz}$	ı	i	2.5 (startup) 0.7 (stabilized)	mA
IDD(HSE)	consumption	C = 10 pF f _{OSC} = 16 MHz	ı	i	2.5 (startup) 0.46 (stabilized)	ША
9 _m	Oscillator transconductance	Startup	3.5	-	-	mA /V
t _{SU(HSE)}	Startup time	V _{DD} is stabilized	-	1	-	ms

Table 29. HSE oscillator characteristics⁽¹⁾⁽²⁾ (continued)

- 1. Resonator characteristics given by the crystal/ceramic resonator manufacturer.
- 2. Guaranteed by characterization results.
- 3. The relatively low value of the RF resistor offers a good protection against issues resulting from use in a humid environment, due to the induced leakage and the bias condition change. However, it is recommended to take this point into account if the MCU is used in tough humidity conditions.
- 4. t_{SU(HSE)} is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

For C_{L1} and C_{L2} , it is recommended to use high-quality external ceramic capacitors in the 5 pF to 25 pF range (typ.), designed for high-frequency applications, and selected to match the requirements of the crystal or resonator (see *Figure 17*). C_{L1} and C_{L2} are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of C_{L1} and C_{L2} . PCB and MCU pin capacitance must be included (10 pF can be used as a rough estimate of the combined pin and board capacitance) when sizing C_{L1} and C_{L2} . Refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website *www.st.com*.

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Input/output AC characteristics

The definition and values of input/output AC characteristics are given in *Figure 19* and *Table 45*, respectively.

Unless otherwise specified, the parameters given in *Table 45* are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 14*.

Table 45. I/O AC characteristics⁽¹⁾

OSPEEDRx [1:0] bit value ⁽¹⁾	Symbol	Parameter	Conditions	Min	Max ⁽²⁾	Unit
	f	Maximum frequency ⁽³⁾	$C_L = 50 \text{ pF}, V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$	-	400	kHz
00	f _{max(IO)out}	Maximum frequency	C _L = 50 pF, V _{DD} = 1.65 V to 2.7 V	-	400	KIIZ
00	t _{f(IO)out}	Output rise and fall time	C _L = 50 pF, V _{DD} = 2.7 V to 3.6 V	-	625	ns
	$t_{r(IO)out}$	Output rise and fail time	$C_L = 50 \text{ pF}, V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$	-	625	115
	f	Maximum frequency ⁽³⁾	C _L = 50 pF, V _{DD} = 2.7 V to 3.6 V	-	2	MHz
01	f _{max(IO)out}	Maximum frequency	C _L = 50 pF, V _{DD} = 1.65 V to 2.7 V	-	1	IVIITZ
01	t _{f(IO)out}	Output rise and fall time	C _L = 50 pF, V _{DD} = 2.7 V to 3.6 V	-	125	ns
	$t_{r(IO)out}$	Output rise and fail time	$C_L = 50 \text{ pF}, V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$	-	250	113
	_	Maximum frequency ⁽³⁾	C _L = 50 pF, V _{DD} = 2.7 V to 3.6 V	-	10	MHz
10	F _{max(IO)out}	waximum nequency	$C_L = 50 \text{ pF}, V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$	-	2	IVII IZ
10	t _{f(IO)out}	Output rise and fall time	C _L = 50 pF, V _{DD} = 2.7 V to 3.6 V	-	25	ns
	$t_{r(IO)out}$	Output rise and fail time	$C_L = 50 \text{ pF}, V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$	-	125	115
	_	Maximum frequency ⁽³⁾	$C_L = 50 \text{ pF}, V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$	-	50	MHz
11	F _{max(IO)out}	waximum nequency	C _L = 50 pF, V _{DD} = 1.65 V to 2.7 V	-	8	IVII IZ
11	t _{f(IO)out}	Output rise and fall time	C _L = 30 pF, V _{DD} = 2.7 V to 3.6 V	-	5	
	t _{r(IO)out}	Output rise and fall time	C _L = 50 pF, V _{DD} = 1.65 V to 2.7 V	-	30	
-	t _{EXTIpw}	Pulse width of external signals detected by the EXTI controller	-	8	-	ns

The I/O speed is configured using the OSPEEDRx[1:0] bits. Refer to the reference manual for a description of GPIO Port configuration register.



^{2.} Guaranteed by design.

^{3.} The maximum frequency is defined in Figure 19.

6.3.17 12-bit ADC characteristics

Unless otherwise specified, the parameters given in *Table 55* are guaranteed by design.

Table 54. ADC clock frequency

Symbol	Parameter		Conditions		Min	Max	Unit
				$V_{REF+} = V_{DDA}$		16	
		Voltage	2.4 V ≤V _{DDA} ≤3.6 V	$V_{REF+} < V_{DDA}$ $V_{REF+} > 2.4 V$		8	
f _{ADC}	ADC clock frequency	ADC clock Range 1 &		$V_{REF+} < V_{DDA}$ $V_{REF+} \le 2.4 \text{ V}$	0.480	4	MHz
			1.8 V ≤V _{DDA} ≤2.4 V	$V_{REF+} = V_{DDA}$		8	
			1.0 v ≥vDDA -	$V_{REF+} < V_{DDA}$		4	
			Voltage Range 3	-		4	

Table 55. ADC characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V_{DDA}	Power supply	-	1.8	-	3.6	V	
V _{REF+}	Positive reference voltage	2.4 V ≤V _{DDA} ≤3.6 V V _{REF+} must be below or equal to V _{DDA}	1.8 ⁽¹⁾	-	V_{DDA}	٧	
V_{REF-}	Negative reference voltage	-	-	V_{SSA}	-	V	
I _{VDDA}	Current on the V _{DDA} input pin	-	-	1000	1450	μA	
I _{VREF} ⁽²⁾	Current on the V _{REF} input	Peak	-	400	700	μA	
	pin	Average	-	400	450	μΑ	
V _{AIN}	Conversion voltage range ⁽³⁾	-	0 ⁽⁴⁾	-	V _{REF+}	V	
f _S	12 hit compling rate	Direct channels	-	-	- 1		
	12-bit sampling rate	Multiplexed channels	-	-	0.76	Msps	
	10 hit compling rate	Direct channels	-	-	1.07	Mone	
	10-bit sampling rate	Multiplexed channels	-	-	0.8 Msp		
	0 hit compling rate	Direct channels	-	-	1.23	Msps	
	8-bit sampling rate	Multiplexed channels	-	-	0.89		
	6-bit sampling rate	Direct channels	-	1.45 1		Msps	
	o-bit sampling rate	Multiplexed channels	-				

Table 55. ADC characteristics (continued)							
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
t _S		Direct channels 2.4 V ≤V _{DDA} ≤3.6 V	0.25	-	-		
		Multiplexed channels 2.4 V ≤V _{DDA} ≤3.6 V	0.56	-	-	- µs	
	Sampling time ⁽⁵⁾	Direct channels 1.8 V ≤V _{DDA} ≤2.4 V	0.56	-	-		
		Multiplexed channels 1.8 V ≤V _{DDA} ≤2.4 V	1	-	-		
		-	4	-	384	1/f _{ADC}	
t _{CONV}	Total conversion time (including sampling time)	f _{ADC} = 16 MHz	1	-	24.75	μs	
		-	4 to 384 phase) approxi	1/f _{ADC}			
C _{ADC}	Internal sample and hold	Direct channels	-	16	-	pF	
	capacitor	Multiplexed channels	-	16	-		
f _{TRIG}	External trigger frequency	12-bit conversions	-	-	Tconv+1	1/f _{ADC}	
	Regular sequencer	6/8/10-bit conversions	-	-	Tconv	1/f _{ADC}	
f _{TRIG}	External trigger frequency Injected sequencer	12-bit conversions	-	-	Tconv+2	1/f _{ADC}	
		6/8/10-bit conversions	-	-	Tconv+1	1/f _{ADC}	
R _{AIN}	Signal source impedance ⁽⁵⁾	-	-	-	50	κΩ	
t _{lat}	Injection trigger conversion	f _{ADC} = 16 MHz	219	-	281	ns	
	latency	-	3.5	-	4.5	1/f _{ADC}	
t _{latr}	Regular trigger conversion	f _{ADC} = 16 MHz	156	-	219	ns	
	latency	-	2.5	-	3.5	1/f _{ADC}	
	5 "			ĺ	<u> </u>		

Table 55. ADC characteristics (continued)

- one constant (max 300 μA)

t_{STAB}

Power-up time

- one variable (max 400 μA), only during sampling time + 2 first conversion pulses.

So, peak consumption is 300+400 = 700 μA and average consumption is 300 + [(4 sampling + 2) /16] x 400 = 450 μA at 1Msps

- V_{REF+} can be internally connected to V_{DDA} and V_{REF-} can be internally connected to V_{SSA}, depending on the package. Refer to Section 4: Pin descriptions for further details.
- 4. V_{SSA} or V_{REF-} must be tied to ground.
- 5. See Table 57: Maximum source impedance RAIN max for RAIN limitations

577

μs

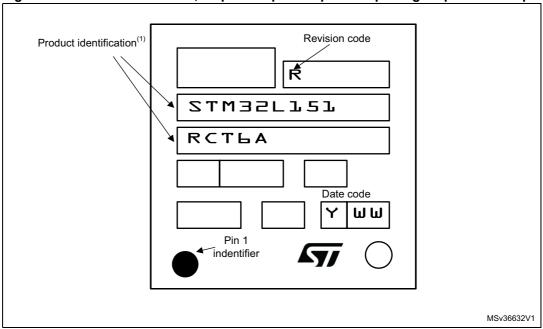
The V_{REF+} input can be grounded if neither the ADC nor the DAC are used (this allows to shut down an external voltage reference).

^{2.} The current consumption through $\ensuremath{V_{REF}}$ is composed of two parameters:

LQFP64 device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

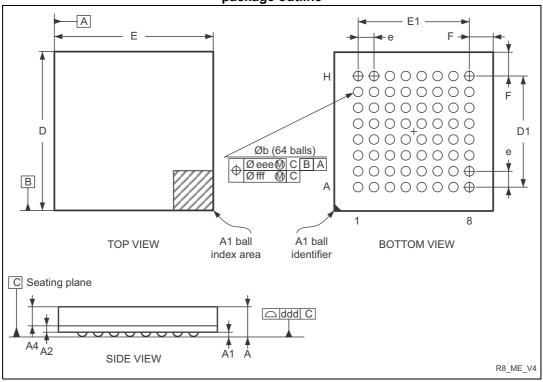
Figure 35. LQFP64 10 x 10 mm, 64-pin low-profile quad flat package top view example



^{1.} Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

7.6 TFBGA64 5 x 5 mm, 0.5 mm pitch, thin fine-pitch ball grid array package information

Figure 45. TFBGA64 5 x 5 mm, 0.5 mm pitch, thin fine-pitch ball grid array package outline



1. Drawing is not to scale.

Table 70. TFBGA64 5 x 5 mm, 0.5 mm pitch, thin fine-pitch ball grid array package mechanical data

Symbol	millimeters			inches ⁽¹⁾			
	Min	Тур	Max	Min	Тур	Max	
Α	-	-	1.200	-	-	0.0472	
A1	0.150	-	-	0.0059	-	-	
A2	-	0.200	-	-	0.0079	-	
A4	-	-	0.600	-	-	0.0236	
b	0.250	0.300	0.350	0.0098	0.0118	0.0138	
D	4.850	5.000	5.150	0.1909	0.1969	0.2028	
D1	-	3.500	-	-	0.1378	-	
Е	4.850	5.000	5.150	0.1909	0.1969	0.2028	
E1	-	3.500	-	-	0.1378	-	
е	-	0.500	-	-	0.0197	-	
F	-	0.750	-	-	0.0295	-	

9 Revision history

Table 74. Document revision history

Date	Revision	Changes		
04-Feb-2014	1	Initial release.		
12-Mar-2014	2	Updated Section 3.5: Low-power real-time clock and backup registers, Section 6.1.2: Typical values and Section 6.3.4: Supply current characteristics. Updated General PCB design guidelines. Updated Table 5: Working mode-dependent functionalities (from Run/active down to standby), Table 14: General operating conditions, Table 21: Current consumption in Low-power run mode, Table 22: Current consumption in Low-power sleep mode, Table 23: Typical and maximum current consumptions in Stop mode, Table 24: Typical and maximum current consumptions in Standby mode, Table 25: Peripheral current consumption, Table 42: I/O current injection susceptibility, Table 66: I/O static characteristics and Table 46: NRST pin characteristics. Updated Figure 14: Current consumption measurement scheme.		
04-Feb-2015 3		Updated DMIPS features in cover page and Section 2: Description Updated max temperature at 105°C instead of 85°C in the whole datasheet. Updated current consumption in Table 20: Current consumption in Sleep mode. Updated Table 25: Peripheral current consumption with new measured values. Updated Table 57: Maximum source impedance RAIN max adding note 2. Updated Section 7: Package information with new package device marking. Updated Figure 9: Memory map.		

